

ENEE2360

Analog Electronics

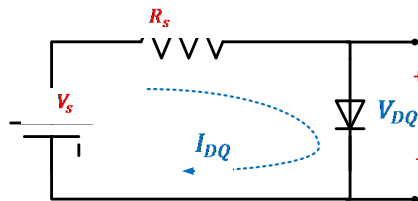
T5A: Diode ac small signal analysis

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Ac Small Signal Analysis

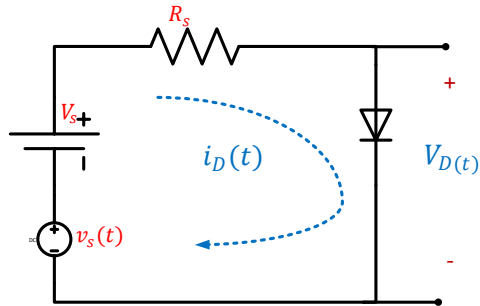
- $I_{DQ} = I_S \left(e^{\frac{V_{DQ}}{\eta V_T}} - 1 \right)$
- And since the diode is forward biased

- $I_{DQ} \approx I_S \left(e^{\frac{V_{DQ}}{\eta V_T}} \right)$



now

- $i_D(t) = I_{DQ} + i_d(t)$
- $V_D(t) = V_{DQ} + v_d(t)$
- $i_D(t) = I_S \left(e^{\frac{V_D(t)}{\eta V_T}} - 1 \right)$



- And since the diode is forward biased

- $i_D(t) = I_S \left(e^{\frac{V_D(t)}{\eta V_T}} \right)$
- $i_D(t) = I_S \left(e^{\frac{V_{DQ} + v_d(t)}{\eta V_T}} \right)$
- $i_D(t) = I_S e^{\frac{V_{DQ}}{\eta V_T}} \cdot e^{\frac{v_d(t)}{\eta V_T}}$
- $i_D(t) = I_{DQ} \left(e^{\frac{v_d(t)}{\eta V_T}} \right)$
- using $e^x = 1+x$; x is very small

but $i_D(t) = I_{DQ} + i_d(t)$

$\therefore i_d(t) = \frac{v_d(t)}{\eta V_T / I_{DQ}} = \frac{v_d}{r_d}$

where $r_d = \frac{\eta V_T}{I_{DQ}} = \frac{V_T}{I_{DQ}}$

$$i_D(t) = I_{DQ} \left(1 + \frac{v_d(t)}{\eta V_T} \right) = I_{DQ} + \frac{v_d(t)}{\eta V_T / I_{DQ}}$$

.

$$\therefore \text{If } V_S(t) = V_S + v_S(t)$$

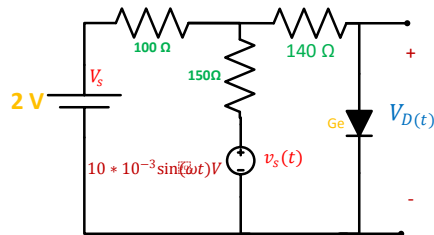
V_S = Dc component

$v_S(t)$ = ac component

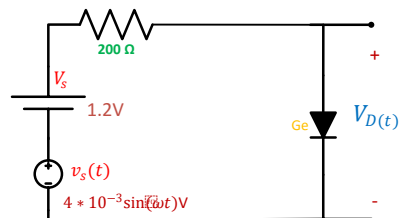
and the amplitude of $v_S(t)$ is small and the diode is always on ; we could use the superposition theorem to find the response ($V_{D(t)}$, $i_D(t)$) .

Example

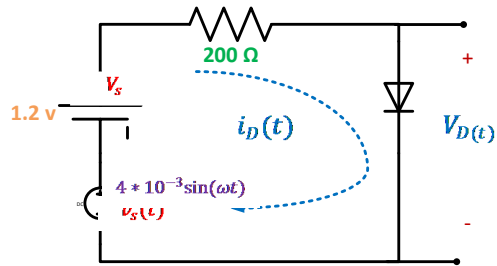
Find $V_D(t)$



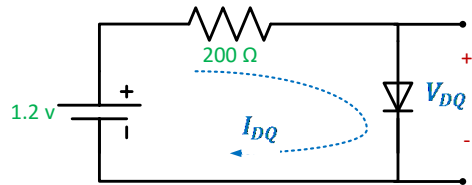
Using Thevenin's Theorem



Since we have a dc source (1.2 V) and an ac signal ($4 \times 10^{-3} \sin \omega t$ V) and the diode is always on ; we use superposition theorem to find $V_D(t)$



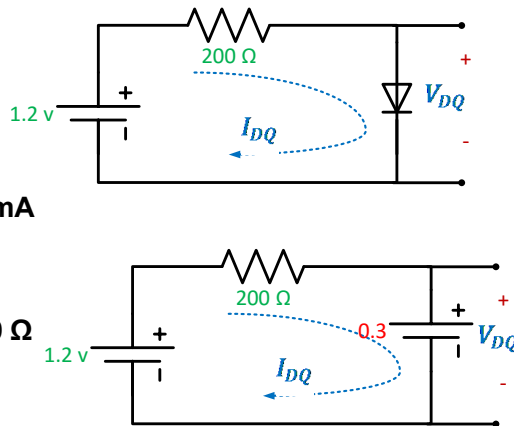
1) to find V_{DQ} (DC Analysis)



$$\therefore V_{DQ} = 0.3 \text{ v}$$

$$\text{and } I_{DQ} = \frac{1.2\text{v} - 0.3\text{v}}{200} = 4.5 \text{ mA}$$

$$\therefore r_d = \frac{V_T}{I_{DQ}} = \frac{25.69\text{mv}}{4.5\text{mA}} = 5.69 \Omega$$



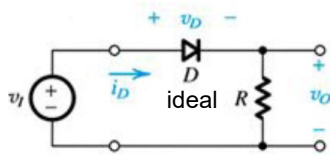
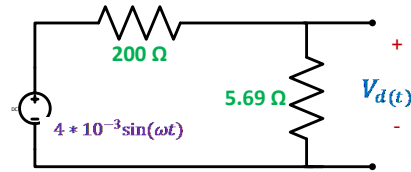
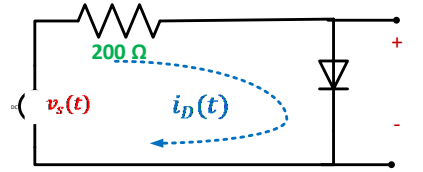
2) To find $V_d(t)$ (ac small signal)

$$v_d(t) = \frac{5.69}{200+5.69} \cdot 4 \times 10^{-3} \sin \omega t \text{ V}$$

$$v_d(t) = 0.1165 \times 10^{-3} \sin \omega t \text{ V}$$

$$\therefore V_D(t) = V_{DQ} + v_d(t)$$

$$V_D(t) = (0.3 + 0.1165 \times 10^{-3} \sin \omega t) \text{ V}$$



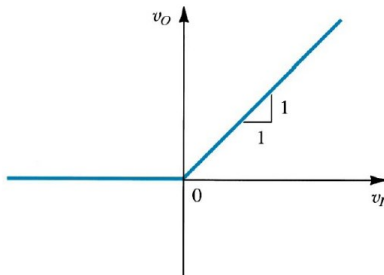
A) when $V_i(t) > 0$, Diode is on (short circuit)

$$\therefore V_o(t) = V_i(t)$$

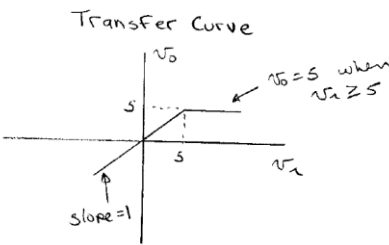
B) when $V_i(t) < 0$, Diode is off (open circuit)

$$\therefore V_o(t) = 0$$

Transfer characteristic curve



Design a diode circuit
that have the given
characteristic curve



Solution

